





	<h2 style="color: red;">ESH3B-E3/57T</h2>
	<p>Hersteller-Teilenummer: ESH3B-E3/57T</p> <hr/> <p>Hersteller / Marke: Vishay / Semiconductor - Diodes Division</p> <hr/> <p>Teil der Beschreibung: DIODE GEN PURP 100V 3A DO214AB</p> <hr/> <p>Datenblätter:  ESH3B-E3/57T.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 13250 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	ESH3B-E3/57T
Hersteller	Vishay / Semiconductor - Diodes Division
Beschreibung	DIODE GEN PURP 100V 3A DO214AB
Kategorie	Diskrete Halbleiterprodukte > Dioden-Gleichrichter-
Teilstatus	13250 pcs Stock
Serie	-
Befestigungsart	Surface Mount
Verpackung / Gehäuse	DO-214AB, SMC
Supplier Device-Gehäuse	DO-214AB, (SMC)
Diodentyp	Standard
Strom - Richt (Io)	3A
Spannung - Forward (Vf) (Max) @ If	900mV @ 3A
Strom - Sperrleckstrom @ Vr	5µA @ 100V
Spannung - Sperr (Vr) (max)	100V
Geschwindigkeit	Fast Recovery = 200mA (Io)
Rückwärts-Erholzeit (Trr)	40ns
Betriebstemperatur - Anschluss	-55°C ~ 175°C
Kapazität @ Vr, F	-
Verpackung	Tape & Reel (TR)



























ESH3B-E3/57T ist neu im Original, Suche ESH3B-E3/57T Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie ESH3B-E3/57T Vishay / Semiconductor - Diodes Division mit Garantie und Vertrauen. Anfrage ESH3B-E3/57T: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>ESH3B-E3/57T Electro-Films (EFI) / Vishay DIODE GEN PURP 100V 3A DO214AB</p>	 <p>ESH3B-M3/57T Vishay / Semiconductor - Diodes Division DIODE GEN PURP 100V 3A DO214AB</p>	 <p>ESH3B-M3/57T Electro-Films (EFI) / Vishay DIODE GEN PURP 100V 3A DO214AB</p>	 <p>ESH3B V7G TSC (Taiwan Semiconductor) DIODE GEN PURP 100V 3A DO214AB</p>
 <p>ESH3B-M3/9AT Electro-Films (EFI) / Vishay DIODE GEN PURP 100V 3A DO214AB</p>	 <p>ESH3B-E3/9AT Vishay / Semiconductor - Diodes Division DIODE GEN PURP 100V 3A DO214AB</p>	 <p>ESH3B V6G TSC (Taiwan Semiconductor) DIODE GEN PURP 100V 3A DO214AB</p>	 <p>ESH3B M6G TSC (Taiwan Semiconductor) DIODE GEN PURP 100V 3A DO214AB</p>

heiße Teile

Mehr

 ESH1PBHM3/84A	 ESH1PC-E3/84A	 ESH1PC-M3/84A	 ESH1PC-M3/84A	 ESH1PCHM3/84A
 ESH1PCHM3/84A	 ESH1PD-E3/84A	 ESH1PD-M3/84A	 ESH1PD-M3/84A	 ESH1PDHM3/84A
 ESH1PDHM3/84A	 ESH2B-E3/52T	 ESH2B-E3/52T	 ESH2C-01M3/5BT-HF	 ESH2C-E3/52T
 ESH2C-E3/52T	 ESH2D-E3/52T	 ESH2D-E3/52T	 ESH2DHE3/52T	 ESH2DHE3/52T
 ESH2DHE3/5BT	 ESH2DHE3/5BT	 ESH2PB-E3/84A	 ESH2PB-E3/84A	 ESH2PB-M3/84A
 ESH2PB-M3/84A	 ESH2PBHM3/84A	 ESH2PBHM3/84A	 ESH2PC-E3/84A	 ESH2PC-E3/84A
 ESH2PC-M3/84A	 ESH2PC-M3/84A	 ESH2PCHM3/84A	 ESH2PCHM3/84A	 ESH2PD-M3/84A
 ESH2PD-M3/84A	 ESH2PDHM3/84A	 ESH2PDHM3/84A	 ESH3B-E3/57T	 ESH3C-E3/57T
 ESH3C-E3/57T	 ESH3D-E3/57T	 ESH3D-E3/57T	 ESH3DHE3/9AT	 ESH3DHE3/9AT
 ESH3DHE3_A1	 ESH3DHE3_A1	 ESHF-A0855M	 ESHF-A085M	 ESHS-C085TA

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